# NX3L4357

Low-ohmic single-pole triple-throw analog switch with enable input

Rev. 5 — 18 June 2012

**Product data sheet** 

### 1. General description

The NX3L4357 is a low-ohmic single-pole triple-throw analog switch suitable for use as an analog or digital 3:1 multiplexer/demultiplexer. It has two digital select inputs (S0 and S1), one digital enable input ( $\overline{E}$ ), three independent inputs/outputs (Y0, Y1 and Y2) and a common input/output (Z). The device features a broadcast mode, when S0 and S1 are both high the signal applied to pin Z is passed to Y0, Y1 and Y2.

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I<sub>CC</sub>. This makes it possible for the NX3L4357 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L4357 allows signals with amplitude up to V<sub>CC</sub> to be transmitted from Z to Yn or Yn to Z. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

### 2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.65  $\Omega$  (typical) at V<sub>CC</sub> = 1.4 V
  - 0.95 Ω (typical) at V<sub>CC</sub> = 1.65 V
  - 0.55  $\Omega$  (typical) at V<sub>CC</sub> = 2.3 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 2.7 V
  - 0.50  $\Omega$  (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - ◆ IEC61000-4-2 contact discharge exceeds 6000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at  $V_{CC} = 3.6$  V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V<sub>CC</sub>
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



## 3. Applications

- Cell phone
- PDA
- Portable media player

## 4. Ordering information

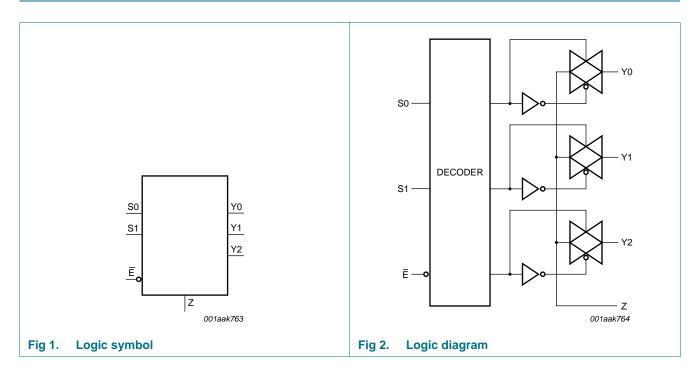
#### Table 1. Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
NX3L4357GM	–40 °C to +125 °C	XQFN10	plastic extremely thin quad flatpackage; no leads; 10 terminals; body $2 \times 1.55 \times 0.5$ mm	SOT1049-3						

## 5. Marking

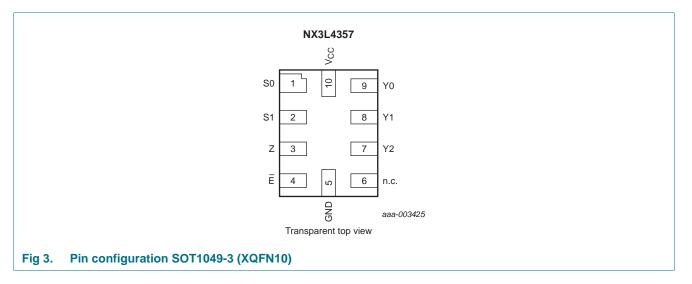
Table 2. Marking	
Type number	Marking code
NX3L4357GM	D43

## 6. Functional diagram



## 7. Pinning information

## 7.1 Pinning



### 7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
S0	1	select input
S1	2	select input
Z	3	common output or input
E	4	enable input (active LOW)
GND	5	ground (0 V)
n.c.	6	not connected
Y2	7	independent input or output
Y1	8	independent input or output
Y0	9	independent input or output
V <sub>CC</sub>	10	supply voltage

## 8. Functional description

Table 4.	Function table <sup>[1]</sup>		
E	S1	S0	Channel on
L	L	L	Y0 = Z
L	L	Н	Y1 = Z
L	Н	L	Y2 = Z
L	Н	Н	Y0, Y1, Y2 = Z (broadcast mode)
Н	Х	Х	switches off

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

### 9. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S0, S1 and $\overline{E}$	<u>[1]</u> –0.5	+4.6	V
V <sub>SW</sub>	switch voltage		[2] -0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 V$	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current	-	±350	mA
		V <sub>SW</sub> > -0.5 V or V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XQFN10 packages: above 132 °C the value of P<sub>tot</sub> derates linearly with 14.1 mW/K.

## **10. Recommended operating conditions**

Table 6.	Recommended operating con	ditions			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.4	4.3	V
VI	input voltage	select input S0, S1 and $\overline{E}$	0	4.3	V
V <sub>SW</sub>	switch voltage	switch input Y0, Y1 and Y2	<u>[1]</u> 0	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC}$ = 1.4 V to 4.3 V	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to select input Sn signal levels.

## 11. Static characteristics

#### Table 7.Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	T <sub>amb</sub> = -40 °C to +125 °C		
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	1.4	-	-	1.4	-	-	V
V <sub>IL</sub>	LOW-level	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	-	0.3	-	0.3	0.3	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.5	-	0.5	0.4	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.5	-	0.5	0.5	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	0.6	-	0.6	0.6	V
I <sub>I</sub>	input leakage current	select input S0, S1 and $\overline{E}$ ; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage	port Y0, Y1 and Y2; see <u>Figure 4</u>							
	current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	±5	-	±10	±100	nA
		$V_{CC} = 3.6 \text{ V} \text{ to } 4.3 \text{ V}$	-	-	±10	-	±50	±200	nA
I <sub>S(ON)</sub>	ON-state	Z port; see Figure 5							
	leakage current	$V_{CC}$ = 1.4 V to 3.6 V	-	-	±5	-	±20	±200	nA
	current	$V_{CC}$ = 3.6 V to 4.3 V	-	-	±10	-	±50	±400	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		V <sub>CC</sub> = 3.6 V	-	-	100	-	300	3000	nA
		V <sub>CC</sub> = 4.3 V	-	-	150	-	500	5000	nA
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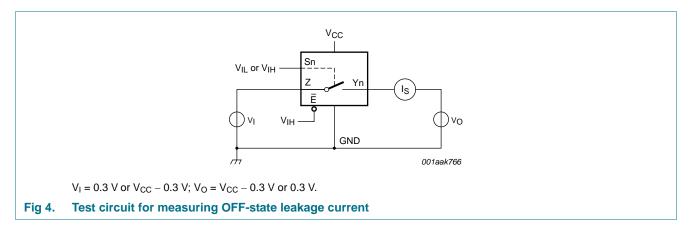
#### Low-ohmic single-pole triple-throw analog switch with enable input

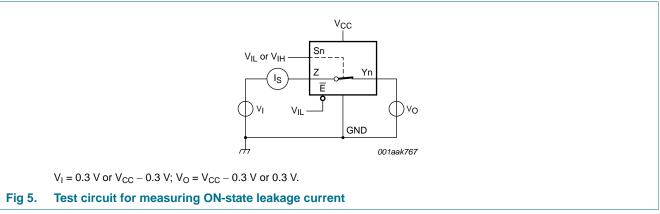
#### Symbol Parameter Conditions T<sub>amb</sub> = 25 °C $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ Unit Min Max Min Max Max Тур (85 °C) (125 °C) $V_{SW} = GND \text{ or } V_{CC}$ additional $\Delta I_{\text{CC}}$ supply current $V_1 = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$ 7 7 2.0 4.0 -μΑ $V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$ 0.35 0.7 1 1 μA - $V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$ \_ 7.0 10.0 \_ 15 15 μΑ $V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$ 5 5 2.5 4.0 -μΑ $V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$ 50 200 300 500 nA --CI input pF \_ 1.0 \_ \_ \_ \_ capacitance OFF-state port Y0, Y1 and Y2 35 C<sub>S(OFF)</sub> -\_ \_ pF \_ capacitance **ON-state** port Z; broadcast mode 330 pF C<sub>S(ON)</sub> ----capacitance port Y0, Y1 and Y2 -170 ---pF

#### Table 7. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

### 11.1 Test circuits





#### 11.2 ON resistance

#### Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

Symbol	Parameter	Conditions	T <sub>amb</sub> =	–40 °C to	+85 °C	$T_{amb} = -40$ °	°C to +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	port Y0, Y1 and Y2; V <sub>I</sub> = GND to V <sub>CC</sub> ; $I_{SW}$ = 100 mA; see Figure 6						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	<u>2]</u>					
		$V_{CC} = 1.4 V$	-	0.20	0.35	-	0.35	Ω
		V <sub>CC</sub> = 1.65 V	-	0.20	0.25	-	0.30	Ω
		$V_{CC} = 2.3 V$	-	0.09	0.13	-	0.15	Ω
		$V_{CC} = 2.7 V$	-	0.09	0.13	-	0.15	Ω
		$V_{CC}$ = 4.3 V	-	0.09	0.13	-	0.15	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	port Y0, Y1 and Y2; $I_{I}^{c}$ V <sub>I</sub> = GND to V <sub>CC</sub> ; I <sub>SW</sub> = 100 mA	3]					
		$V_{CC} = 1.4 V$	-	1.05	3.35	-	3.65	Ω
		V <sub>CC</sub> = 1.65 V	-	0.55	1.25	-	1.35	Ω
		$V_{CC} = 2.3 V$	-	0.20	0.35	-	0.40	Ω
		$V_{CC} = 2.7 V$	-	0.18	0.35	-	0.40	Ω
		$V_{CC} = 4.3 V$	-	0.23	0.40	-	0.45	Ω

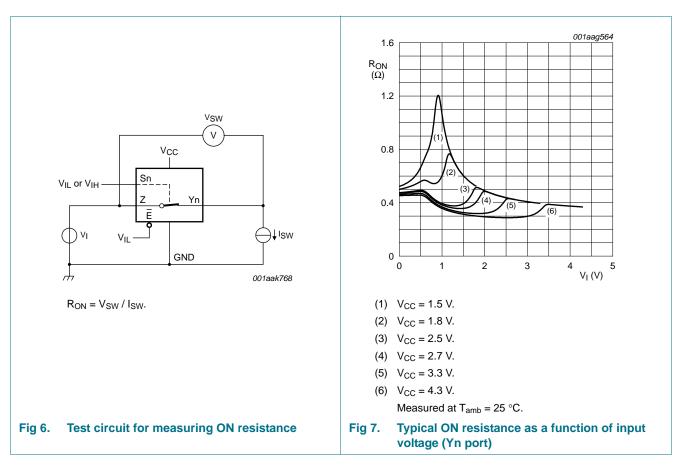
[1] Typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ .

[2] Measured at identical  $V_{CC}$ , temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

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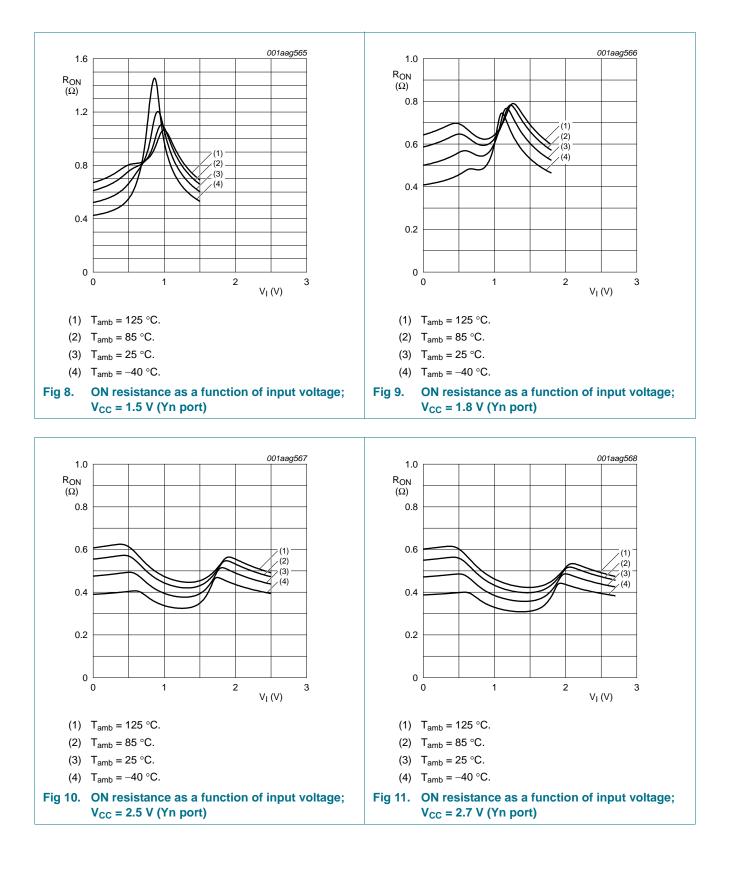
Low-ohmic single-pole triple-throw analog switch with enable input



### 11.3 ON resistance test circuit and graphs

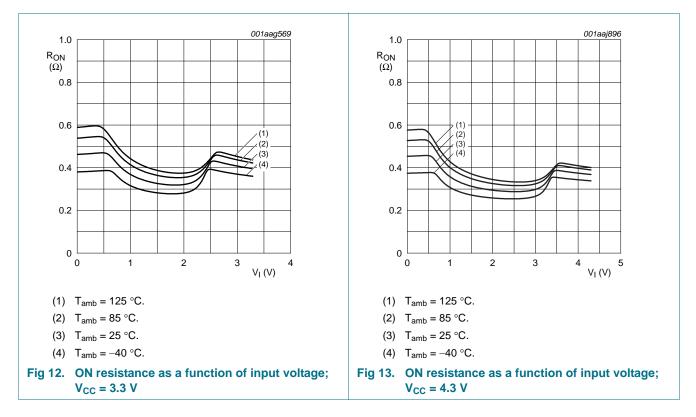
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#### Low-ohmic single-pole triple-throw analog switch with enable input



## **12. Dynamic characteristics**

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 16.

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	Ē, Sn to Z or Yn; see <u>Figure 14</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	50	100	-	120	125	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	36	75	-	85	95	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	24	50	-	55	60	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	22	45	-	45	50	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	22	45	-	45	50	ns
t <sub>dis</sub>	disable time	Ē, Sn to Z or Yn; see <u>Figure 14</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	32	80	-	90	105	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	20	65	-	70	75	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	12	30	-	35	40	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	10	25	-	30	35	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	10	25	-	30	35	ns

Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	-
t <sub>b-m</sub>	break-before-make	see Figure 15	[2]						1	
time	time	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		-	19	-	9	-	-	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		-	17	-	7	-	-	ns
		$V_{CC}$ = 2.3 V to 2.7 V		-	13	-	4	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-	10	-	3	-	-	ns
		$V_{CC}$ = 3.6 V to 4.3 V		-	10	-	2	-	-	ns

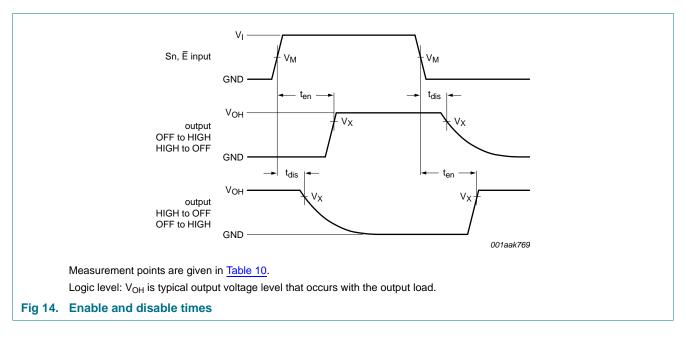
#### Table 9. Dynamic characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 16.

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

### 12.1 Waveforms and test circuits

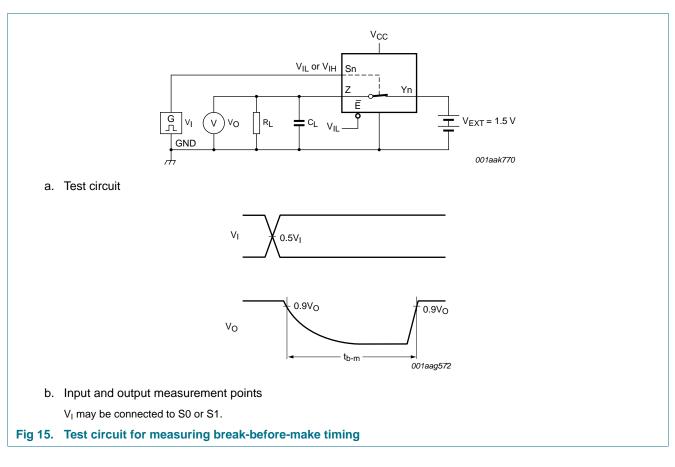


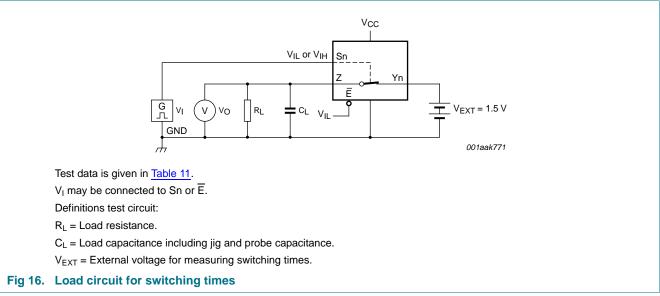
#### Table 10. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

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#### Table 11. Test data

Supply voltage	Input		Load	
V <sub>cc</sub>	V <sub>I</sub> t <sub>r</sub> , t <sub>f</sub>		CL	RL
1.4 V to 4.3 V	V <sub>CC</sub>	$\leq$ 2.5 ns	35 pF	50 Ω

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### 12.2 Additional dynamic characteristics

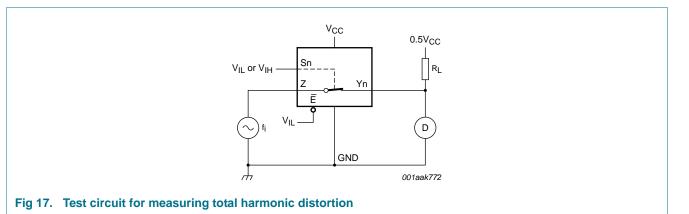
#### Table 12. Additional dynamic characteristics

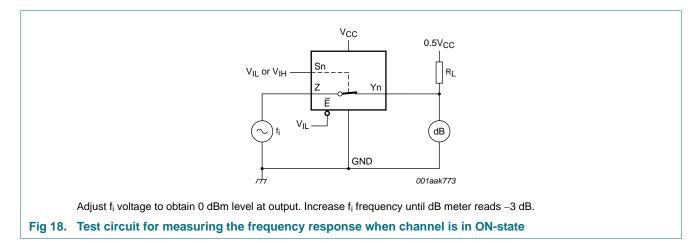
At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns.

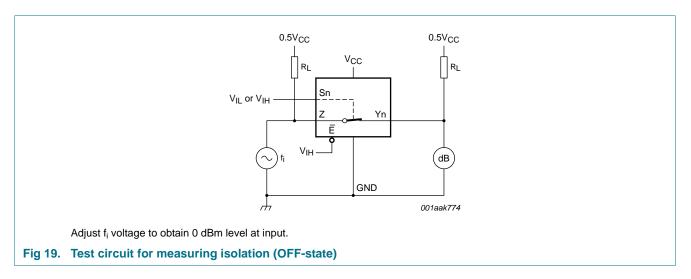
Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C			Unit
				Min	Тур	Max	
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$ ; see Figure 17	<u>[1]</u>				1
		V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)		-	0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)		-	0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)		-	0.02	-	%
		V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = 2 V (p-p)		-	0.02	-	%
		V <sub>CC</sub> = 4.3 V; V <sub>I</sub> = 2 V (p-p)		-	0.02	-	%
		$V_{CC}$ = 3.0 V; $V_{I}$ = 1 V (p-p); $R_{L}$ = 600 $\Omega$		-	0.01	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L = 50 \Omega$ ; see Figure 18	<u>[1]</u>				
	response	port Y0, Y1 or Y2; $V_{CC}$ = 1.4 V to 4.3 V		-	30	-	MHz
		port Y0, Y1 and Y2; $V_{CC}$ = 1.4 V to 4.3 V		-	20	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 19}}{100 \text{ kHz}}$	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$		-	-90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 20					
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$		-	0.21	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	0.30	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$ ; $R_L = 50 \Omega$ ; see Figure 21	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		-	-90	-	dB
Q <sub>inj</sub>	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; see Figure 22$					
		$V_{CC} = 1.5 V$		-	10	-	рС
		V <sub>CC</sub> = 1.8 V		-	15	-	рС
		$V_{CC} = 2.5 V$		-	26	-	рС
		$V_{CC} = 3.3 V$		-	36	-	рС
		$V_{CC} = 4.3 V$		-	50	-	рС

[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

### 12.3 Test circuits



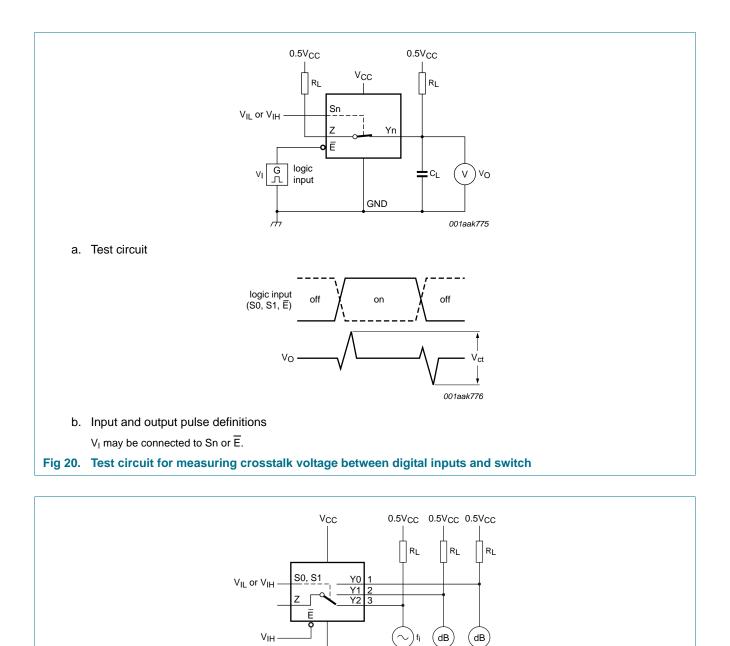




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#### Low-ohmic single-pole triple-throw analog switch with enable input

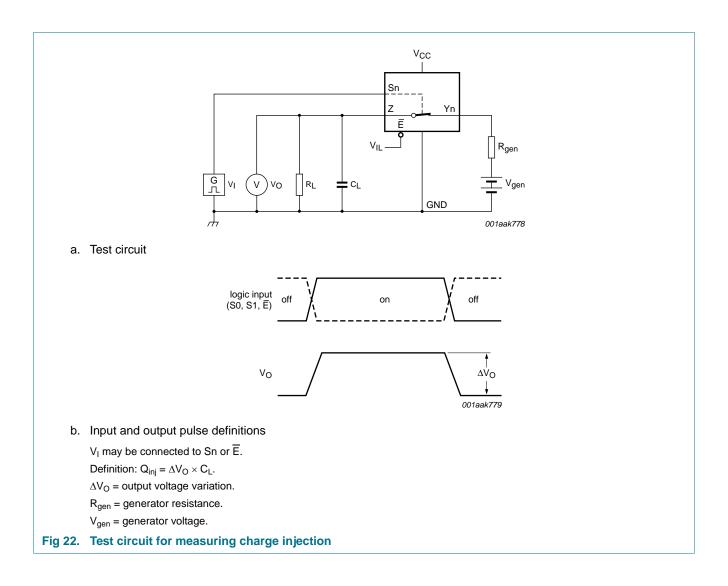


GND f<sub>i</sub> may be connected to Y0, Y1 or Y2.
Fig 21. Test circuit for measuring crosstalk between switches

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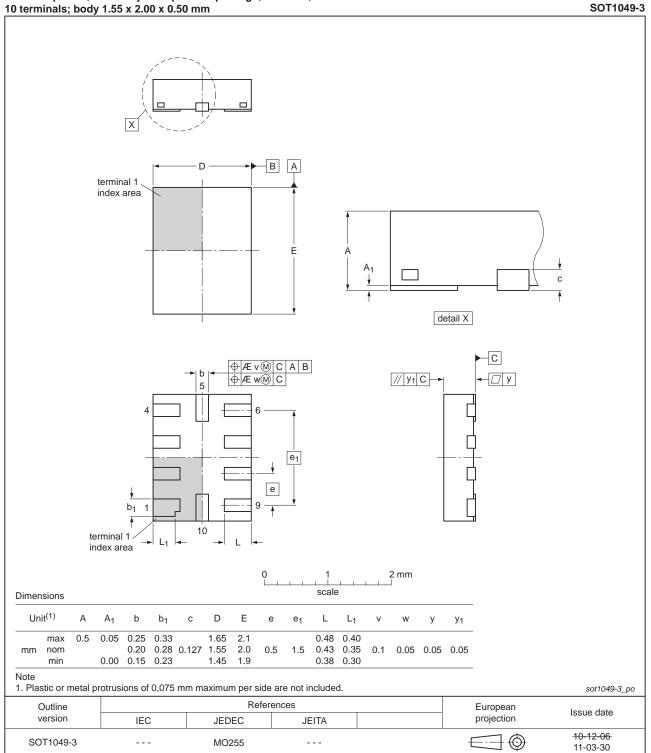
#### Low-ohmic single-pole triple-throw analog switch with enable input



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Low-ohmic single-pole triple-throw analog switch with enable input

## 13. Package outline



#### XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.55 x 2.00 x 0.50 mm

Fig 23. Package outline SOT1049-3 (XQFN10)

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## 14. Abbreviations

Table 13. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal-Oxide Semiconductor			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			

## **15. Revision history**

#### Table 14.Revision history

De sum sui ID	Delesse dete	Data alcost status		Our and a data
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L4357 v.5	20120618	Product data sheet	-	NX3L4357 v.4
Modifications:	<ul> <li>Package or</li> </ul>	utline drawing SOT1049-2 c	hanged to SOT1049-3 (	Figure 23).
NX3L4357 v.4	20111107	Product data sheet	-	NX3L4357 v.3
Modifications:	<ul> <li>Legal page</li> </ul>	s updated.		
NX3L4357 v.3	20101228	Product data sheet	-	NX3L4357 v.2
NX3L4357 v.2	20100428	Product data sheet	-	NX3L4357 v.1
NX3L4357 v.1	20091019	Product data sheet	-	-

## 16. Legal information

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Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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#### Low-ohmic single-pole triple-throw analog switch with enable input

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## NX3L4357

Low-ohmic single-pole triple-throw analog switch with enable input

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